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Citation	Nanotechnology, 26(23), 235602 https://doi.org/10.1088/0957-4484/26/23/235602
Issue Date	2015-05-20
Doc URL	http://hdl.handle.net/2115/61676
Type	article (author version)
File Information	GENKI_Si_ver7_plane.pdf



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Solution plasma synthesis of Si nanoparticles

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Abstract. Silicon nanoparticles (Si-NPs) were directly synthesized from a Si bar electrode via a solution plasma. In order to produce smaller Si-NPs, the effects of different electrolytes and applied voltages on the product were investigated in the experiments detailed in this paper. The results demonstrated that the use of an acidic solution of 0.1 M HCl or HNO₃ produced Si-NPs without SiO₂ formation. According to the TEM and electron energy-loss spectroscopy, the obtained Si-NPs contained both amorphous and polycrystalline Si particles, among which the smaller Si-NPs tended to be amorphous. When an alkaline solution of K₂CO₃ was used instead, amorphous SiO₂ particles were synthesized owing to the corrosion of Si in the high-temperature environment. The pH values of KCl and KNO₃ increased during electrolysis, and the products were partially oxidized in the alkaline solutions. The particle size increased with an increasing applied voltage because the excitation temperature of the plasma increased.

1. Introduction

Lithium-ion batteries (LIBs) have been widely used as energy-storage devices for applications such as portable electronic devices and electric vehicles. Current commercial LIBs, with graphite and other carbonaceous materials as standard anode materials, have a maximum theoretical capacity of 372 mAh·g⁻¹ because of the limited lithium storage sites within sp²-hybridized carbon hexahedrons corresponding to the intercalation of Li₆C. Among the new anode materials with higher capacities than those available commercially, silicon anodes have attracted much attention because of their high theoretical capacity of 3579 mAh·g⁻¹, allowing

them to form a $\text{Li}_{15}\text{Si}_4$ alloy at room temperature [1-3]. During the lithium insertion–extraction process, however, a large volume change (>280%) inevitably occurs, which leads to pulverization of the silicon anode and loss of electrical contact to the current collector, resulting in poor cycling performance [2, 4]. To mitigate this volume-change issue, several strategies have been proposed, including reducing the particle size to nanoscale [5, 6] and dispersing nano-Si in the conductive carbon matrix to form a Si–carbon composite [7-10]. Liu et al. (2012) reported that the critical particle diameter needs to be below 150 nm to avoid the surface cracking and subsequent fracturing during lithiation [4]. In addition, dispersing silicon nanoparticles (Si-NPs) into a carbon matrix is a technique that has been well developed, in which the carbonaceous material acts as a buffer to the volume expansion and improves the electrical conductivity of Si active materials [7].

To produce nanomaterials, various types of solution plasma have been employed [11-17]. The solution plasma technique offers many advantages, including (1) a simple experimental setup, (2) use of readily available precursors, (3) no requirement for harmful chemicals, (4) higher productivity than conventional solution processes, and (5) suitability for mass production. From the viewpoint of electrode configuration and power source, solution plasma techniques can be subdivided into four main groups:

- (i) Gas discharge between an electrode and the electrolyte surface.
- (ii) Direct discharge between two electrodes.
- (iii) Contact discharge between an electrode and the surface of the surrounding electrolyte.
- (iv) Radio frequency (RF) and microwave (MW) plasma in liquid.

For Si nanoparticle synthesis, Tokushige et al. reported the plasma-induced cathodic discharge electrolysis, in which the plasma was generated above the electrolyte surface in the Ar atmosphere (group i) [18]. The arc discharge in liquid has been applied to synthesize Si nanowire and Si-NPs, in which the distance between two Si electrodes was approximately 1 mm (group ii) [19, 20]. Recently, contact glow discharge electrolysis (CGDE) was also used to synthesize Si-NPs (group iii) [16, 21]. In CGDE, the plasma is generated surrounding the electrode in the conductive electrolyte. In comparison to the arc discharge, the current was relatively small under a high voltage. Since lower current led to a decrease in electrode temperature, the Sn nanoparticles were produced using CGDE to improve the capacity of LIBs [22, 23]. In this study, we investigated the effect of the electrolyte and the applied voltage on the product in order to fabricate smaller Si-NPs by solution plasma with CGDE. To study the plasma properties, the light emission of plasma was analyzed using spectroscopy. The obtained particles were characterized by scanning electron microscopy (SEM), transmission electron microscopy (TEM), and electron energy-loss spectroscopy (EELS).

2. Experimental

Figure 1 shows the experimental setup for producing Si particles. A B-doped square-cross section Si bar with a width of 5.0 mm (Shin-Etsu Chemical Co., Ltd.), and an electric resistance of 0.00494–0.00478 $\Omega\cdot\text{cm}$ was used as the cathode. It was placed in a glass cell with a cooling jacket, and the upper part of the Si bar was shielded by a quartz glass tube to generate a plasma at the bottom tip of the electrode. A voltage was applied using a direct current power supply (ZX800H, Takasago). To study the effect of different electrolytes, 300-mL solutions of 0.1 M K_2CO_3 , KCl, KNO_3 , HCl, and HNO_3 were used in separate experiments. The voltage was varied at three different levels for each electrolyte, as shown in table 1. The high voltage corresponds to the maximum voltage that can be safely applied to the plasma over a long period. The low voltage corresponds to the voltage level used to initiate plasma generation with light emission. Before electrolysis, the solution was heated to a temperature above 60 °C. During electrolysis, the solution was stirred using a magnetic stirrer at a rate of 300 rpm, and the plasma was generated for 1 h. The light emission from the plasma was measured using a visible-light spectrophotometer (USB 2000+, Ocean Optics). After the synthesis, the products were collected by centrifugation and then washed several times with deionized water. The products were then characterized using a scanning electron microscope (JSM-7001FA, JEOL) and a field-emission transmission electron microscope (JEM-2010F, JEOL) with an EELS detector.

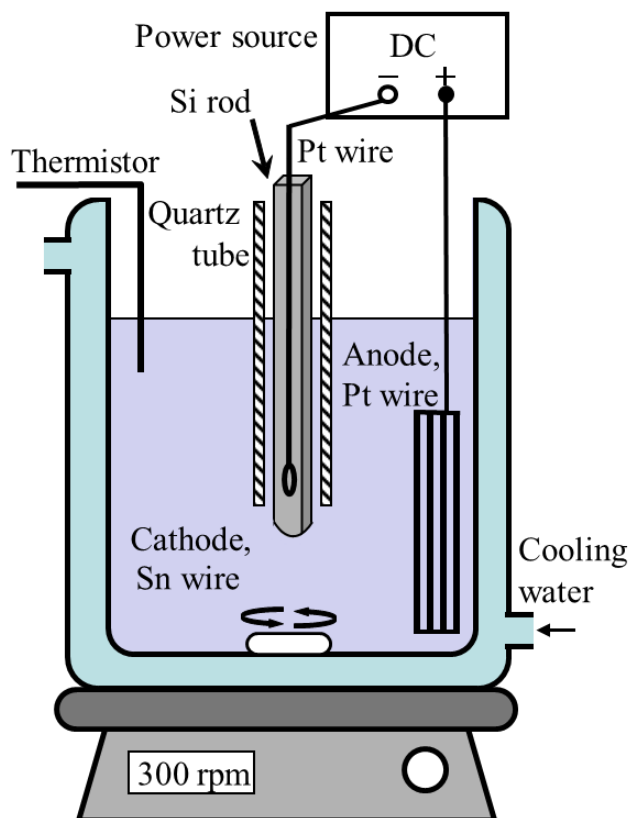


Figure 1. (color online) Experimental setup for producing Si particles. A Si rod electrode was placed in a glass cell with a cooling jacket, in which the upper part of the Si rod was shielded by a quartz glass tube to generate plasma at the bottom tip of the electrode.

Table 1. Applied voltage at each electrolyte.

Voltage (V)	K ₂ CO ₃	KCl	HCl	KNO ₃	HNO ₃
High voltage	200	230	200		
Middle voltage	180	210	180	230	160
Low voltage	160	190	160	210	140

3. Results and discussions

3.1. Plasma generation

The discharge plasma with light emission was generated around the Si electrode at various voltage levels shown in table 1. Figure 2 shows the typical current–voltage curve in the 0.1 M HCl solution. When the voltage was increased, the current first increased and then decreased. Below 1.3 V, no current flowed because the electrolysis of water did not occur. The linear current increase with voltage, in accordance with Ohm’s law, corresponds to the occurrence of electrolysis of water. Since the thermal loss was concentrated at the cathode–solution interface,

the solution near the Si electrode was heated to the boiling point and a gas layer consisting of steam was generated. Once the gas layer was generated at the surface of the cathode, the cathode and the solution were no longer in contact with each other and the current decreased. When the voltage was sufficiently high (>150 V), a discharge with intense light emission began in the gas layer. In our experiments, the voltage was set to three different levels, namely ‘low’, ‘middle’, and ‘high’. The plasma generation was continued at 1 h to produce nanoparticles.

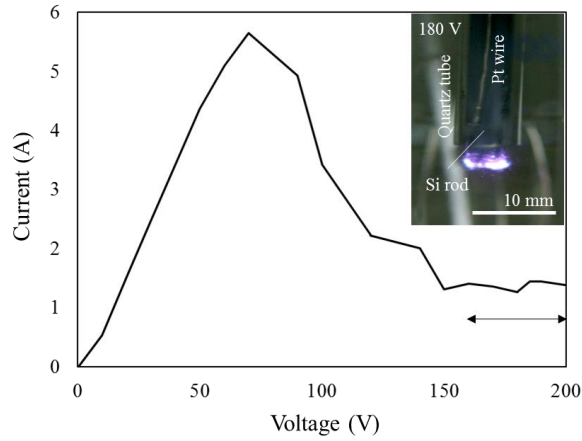


Figure 2. (color online) Current–voltage curve in 0.1 M HCl solution. Above 150 V, plasma generation with light emission occurred and the intensity of the light emission increased with increases in voltage. The inset shows a photograph of the electrode at 180 V.

To characterize the generated plasma, the light emission spectra were obtained by an optical fibre spectrometer. Figure 3(a) shows the spectra from the electrode in different electrolytes, in which the spectra contained emissions of the OH $A^2\Sigma^+ - X^2\Pi$ (0, 0) band (309 nm), H_α (656 nm) and H_β (486 nm) as the Balmer atomic hydrogen lines, and O (777 nm). The emission lines at 385, 413, 505, and 635 nm correspond to Si II as an electrode material. When KCl, KNO_3 , or K_2CO_3 were used as the electrolyte, strong emission of K (769.9 and 766.5 nm) was detected. These results agree with those reported for other solution plasmas [14, 24]. The excitation temperature was calculated from the Boltzmann plot by assuming local thermodynamic equilibrium (LTE) [25] as follows:

$$\ln \left(\frac{I_{ij} \lambda_{ij}}{g_i A_{ij}} \right) = - \frac{E_i}{kT} + \ln \left(\frac{N(T)}{U(T)} \right), \quad (1)$$

where I_{ij} is the emission intensity of H_α (656 nm) and H_β (486 nm), λ_{ij} is the wavelength, g_i is the statistical weight of the upper level, A_{ij} is the transition probability, E_i is the upper level

energy, k is the Boltzmann constant, $N(T)$ is the total number density of neutrals, and $U(T)$ is the partition function. Figure 3(b) shows the excitation temperatures calculated for different electrolytes and applied voltages. The higher applied voltage excited the plasma and the excitation temperatures ranged from 4500 to 7000 K. Compared to other solution plasmas, this value is relatively high. In the case of a microwave plasma and a high-frequency plasma in a liquid [25-27], for example, the excitation temperatures ranged from approximately 3000 to 5500 K. In our plasma, the net area of discharge was considered to be low and the plasma was generated at current concentration spots. Therefore, the average temperature of the electrode surface was low. However, the average temperature of Si electrode is still higher than that of conventional metal electrodes because of the higher electric resistance of Si and the higher surface temperature excited the plasma.

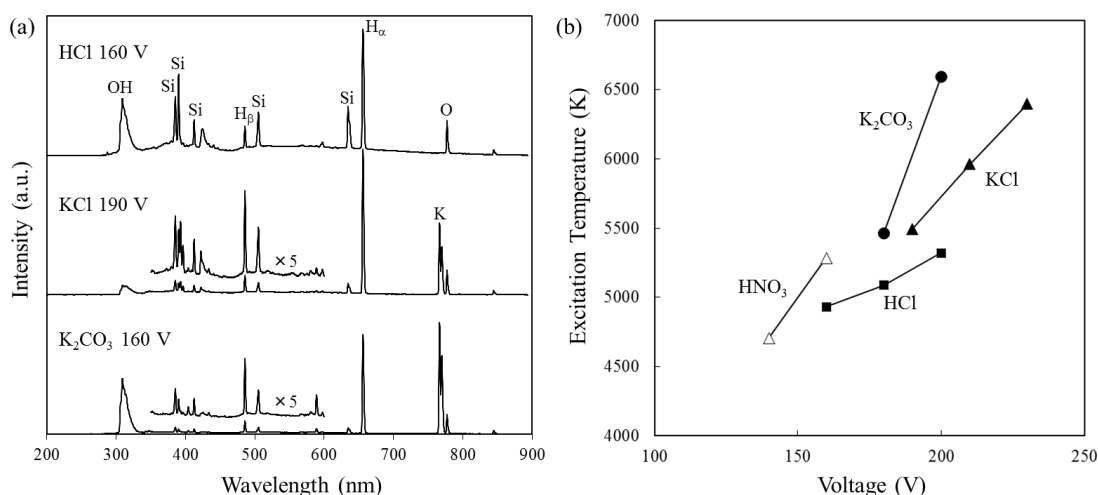


Figure 3. (a) Spectra of the electrode in different electrolytes. (b) Excitation temperature versus applied voltage in different electrolytes. The excitation temperatures were calculated from the intensity of the light emission of H_α (656.3 nm) and H_β (486.1 nm) when the electrons were assumed to have a Boltzmann distribution.

3.2. Characterization of the synthesis products

The produced particles were dispersed in a solution, and a cooling jacket was used to reduce the solution temperature to below 70 °C. The products obtained from the plasma electrolysis were collected by centrifugation and characterized by SEM. As shown in the SEM image (figure 4), the products synthesized in different electrolytes at different applied voltages were spherical in shape. Various spots of the Si bar was partially melted or ionized by the plasma and then immediately solidified to form spherical particles. For each electrolyte, a higher applied

voltage increased the particle size because of the higher excitation temperature. When the applied voltage was low, the particle size decreased to less than 1 μm . When KCl and K_2CO_3 solutions were used as the electrolyte, the respective products contained thin film-like particles, which might be a corrosion product precipitated during the drying process. The average current and electrode consumption are summarized in Fig. 5. At each electrolyte, the current decreased with an increase in the applied voltage. When the applied voltage was increased, a thick gas layer formed that prevented current flow. To estimate the amount of particles produced, the difference between the electrode weights before and after the experiments was measured, as shown in Fig. 5(b). In the case of 180 V in 0.1 M HCl solution, 17.8 mg of the product was produced during 1 h with an applied electric power of 180 Wh. When the discharge area is increased and discharge continues, the production rate will increase.

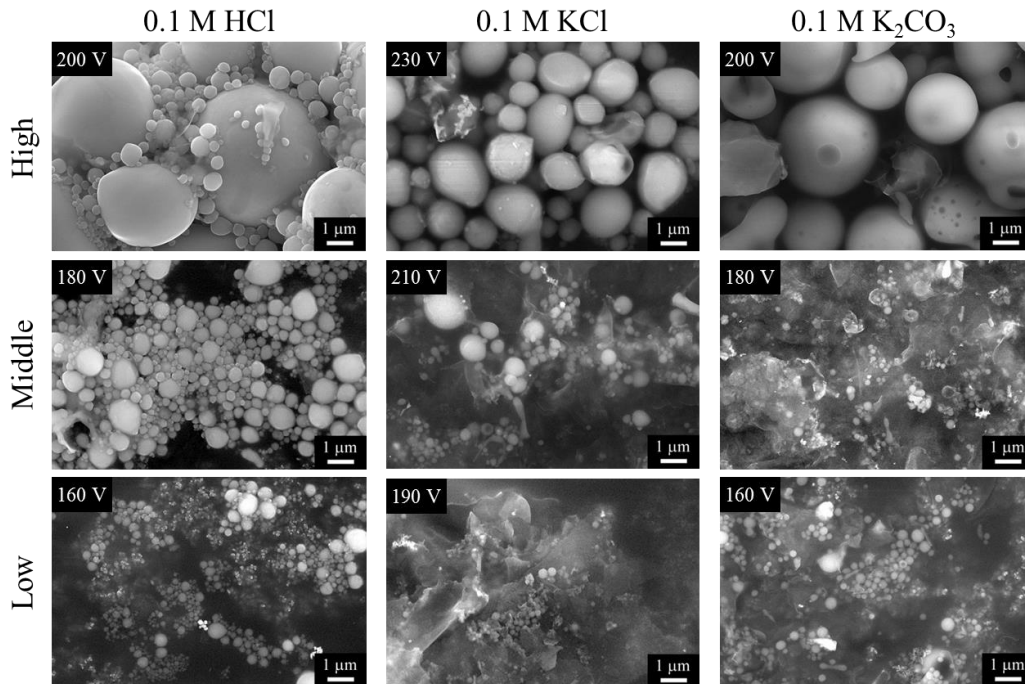


Figure 4. SEM image of Si particles produced in different electrolytes at different applied voltages.

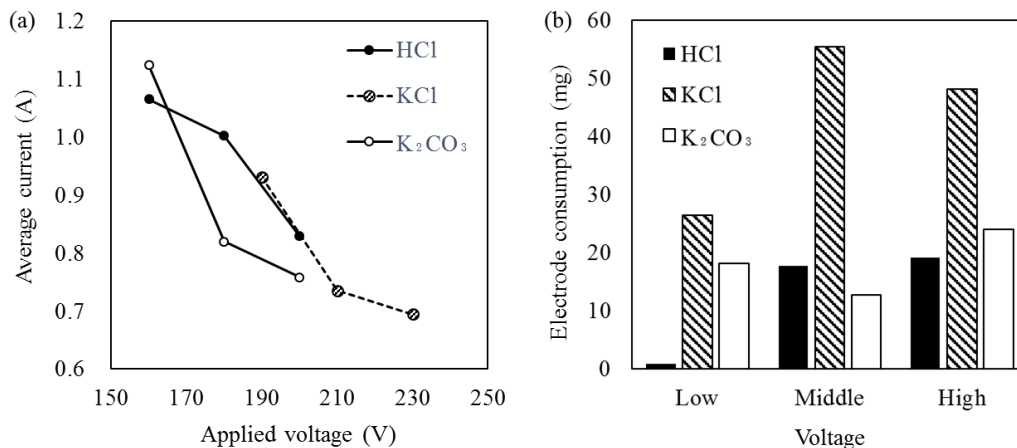


Figure 5 (a) Relationship between the applied voltage and average current for different electrolytes. (b) Electrode consumption at different conditions.

Based on TEM observation of the particles shown in figure 5, they were classified into 4 types: (a) single crystalline Si, (b) polycrystalline Si, (c) amorphous-like Si, and (d) amorphous SiO₂. The product phase strongly depended on the electrolyte used. When acidic solutions of HCl and HNO₃ were used as the electrolyte, the amorphous SiO₂ particles were not detected. In contrast, the alkaline solution of K₂CO₃ produced only amorphous SiO₂, in which no Si particles could be found. Diffraction patterns and EEL spectra of the four types of Si particles are also shown in figure 6. By analysing the energy-loss near-edge structure of Si-L_{2,3} in EELS, the electronic structure of Si could be determined [28, 29]. In figure 6(a,b), the diffraction patterns and EEL spectra match those of Si. Amorphous Si-NPs were also formed, as shown in figure 5(c). Si-NPs were mainly synthesized when the acidic solutions of HCl and HNO₃ were used, and crystalline structures were different owing to the difference in cooling rates during solidification. When the particles were immediately quenched, amorphous Si particles were generated. It is considered that the cooling rate increased in the following order: (a) single-crystalline Si < (b) polycrystalline Si < (c) amorphous-like Si. The enlarged TEM image of the single-crystalline Si particle shown in Fig. 7 revealed that the oxide layer with a thickness of 3–4 nm existed on the Si surface. This oxide layer was generated during melting and solidification under a high-temperature atmosphere. Figure 6(d) shows amorphous SiO₂ nanoparticles produced by the alkaline K₂CO₃ solution, whose EEL spectrum agrees with that of the SiO₂ phase. When neutral solutions of KCl and KNO₃ were used, both Si and SiO₂ particles were produced. At certain hot spots on the electrode surface during the plasma electrolysis, the Si²⁺ ions were generated and they combined with OH⁻ to form SiO₂: $\text{Si}^{2+} + 2\text{OH}^- \rightarrow \text{Si}(\text{OH})_2 \rightarrow$

SiO₂ + H₂O. Etching of Si in KOH and NaOH was also reported by other research groups [30, 31]. Thus, the pH value of the electrolyte might have affected the product phase.

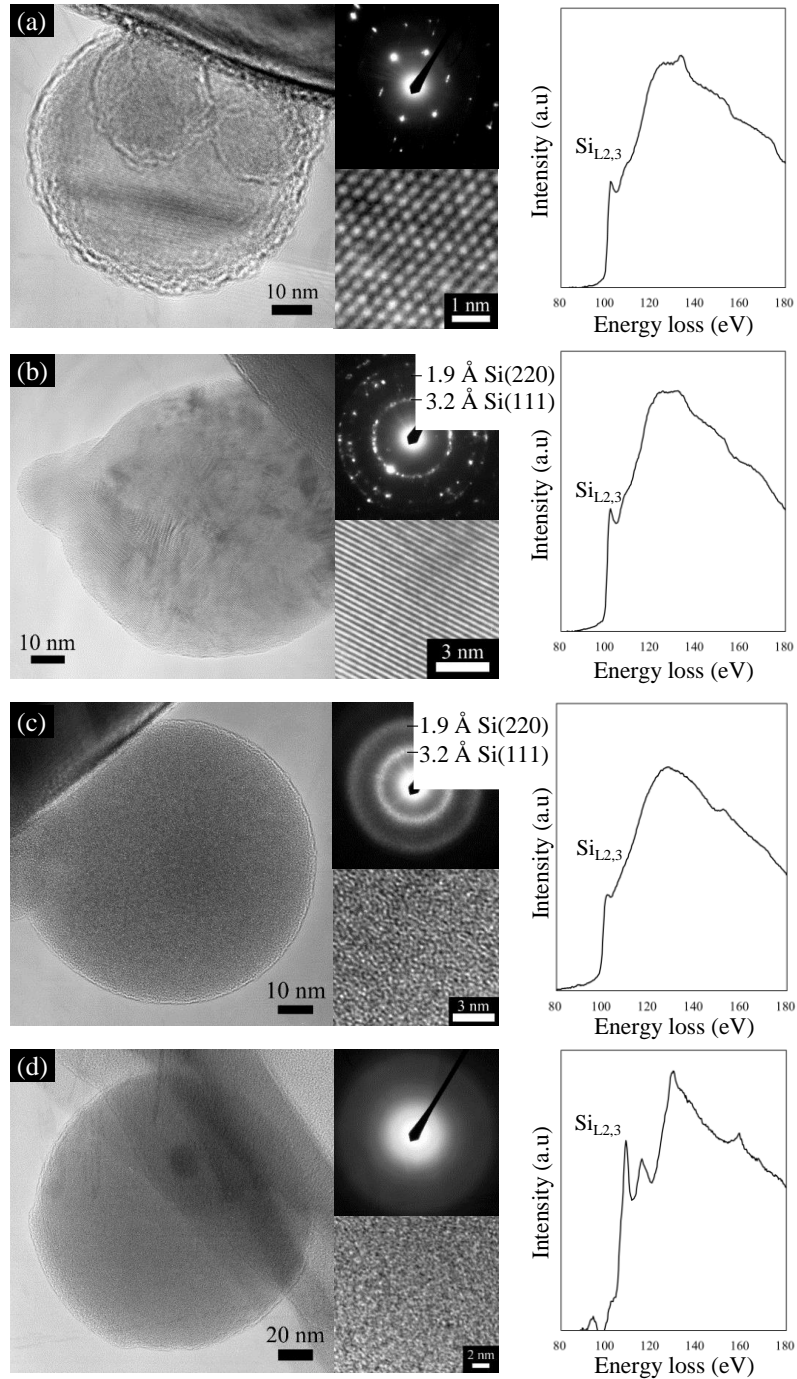


Figure 6. TEM images, diffraction patterns, and high-resolution TEM images of different types of (a) single-crystalline Si, (b) polycrystalline Si, (c) amorphous-like Si, and (d) amorphous SiO₂ nanoparticles. The graphs on the right side show the corresponding EEL spectra of the

particles. The spectra of particles in (a–c) agree with those of Si and the amorphous particles in (d) were detected in SiO₂.

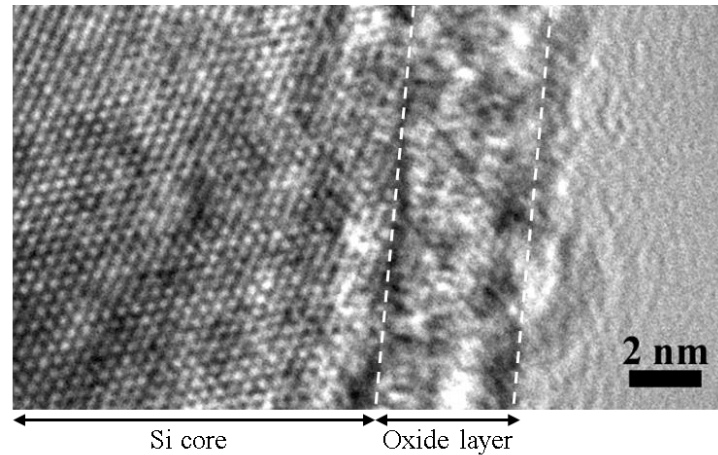


Figure 7. Enlarged TEM image of Si-NP produced in HNO₃ solution. The oxide layer with a thickness of 3–4 nm was formed on the Si surface.

Figure 8 shows the change in pH during plasma electrolysis in different electrolytes. When the electrolyte was either a strong acid or strong base, the pH remained constant. The pH of KNO₃ and KCl increased during electrolysis because of the consumption of negative ions and formation of OH⁻ ions. In principle, the electrolysis of an acidic solution can be described as follows:



However, the reduction of Cl⁻ ions was favoured over the decomposition of H₂O:



Therefore, the pH in the neutral solution increased owing to the generation of Cl₂ gas, and oxide particles were then formed to react with the OH⁻ ions, which produced Cl⁻ ions instead. In the case of the KNO₃ solution as the electrolyte, the reduction of NO₃⁻ to NO₂⁻ might occur at the cathode electrode [32].



Table 2 summarizes the pH values and product compositions. After 2 weeks, the pH did not change considerably from the values after electrolysis. From these results, it is clear that the use of an acidic solution as the electrolyte was effective for producing Si-NPs.

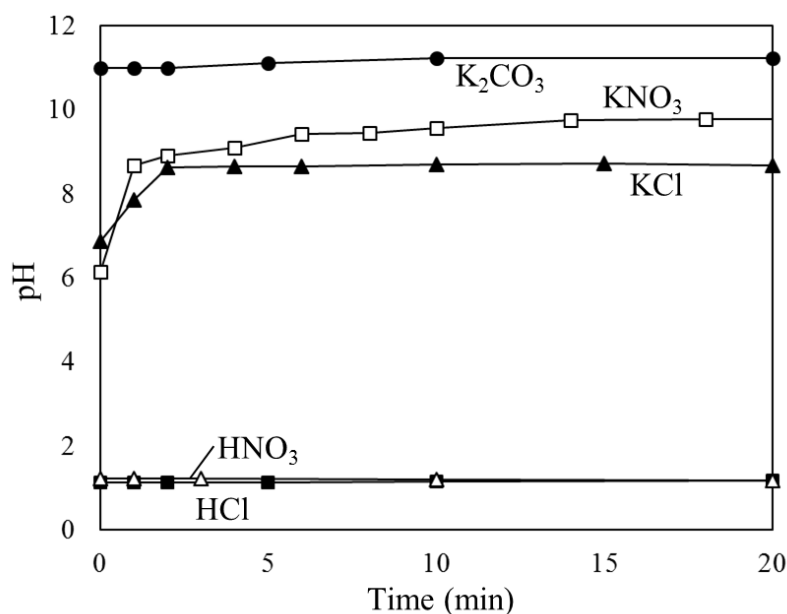


Figure 8. Changes in pH values during plasma electrolysis in different electrolytes. When the neutral solutions of KNO₃ and KCl were used, the pH value was increased owing to the consumption of Cl⁻ and KNO₃⁻ ions.

Table 2. pH values and product composition.

Solution	Initial pH value	pH value after electrolysis	pH value after 2 weeks	Products
0.1 M K ₂ CO ₃	11.00	11.18	10.89	SiO ₂
0.1 M KNO ₃	6.13	9.88	9.87	Si + SiO ₂
0.1 M KCl	6.87	8.71	8.39	Si + SiO ₂
0.1 M HNO ₃	1.21	1.10	1.06	Si
0.1 M HCl	1.12	1.24	1.23	Si

Figure 9 shows the size distribution of particles obtained from plasma electrolysis in 0.1 M HNO₃ at an applied voltage of 140 V. The 363 particles were analysed by TEM to distinguish the crystal structures. Most of the particles produced had diameters ranging from 50 to 100 nm. The TEM analysis showed that the smaller particles with diameters below 100 nm contained the amorphous phase and the ratio of this amorphous phase increased with decreasing particle size. When the Si precursor of Si liquid, vapour, or ions was cooled immediately, amorphous Si-NPs

were produced. In contrast, the coarse crystalline particles with diameters above 100 nm are believed to have been synthesized via solidification of the liquid silicon droplets generated on the Si electrode surface. When these Si-NPs are used for a battery anode, their crystalline structure might affect the battery performance. It is reported that the critical size for fracture is larger for amorphous Si spheres, and the lithiation reaction rate is approximately constant and does not slow as in the case of crystalline Si [33]. Therefore, amorphous Si nanoparticles are expected to more effectively prevent fracture during the first lithiation cycle.

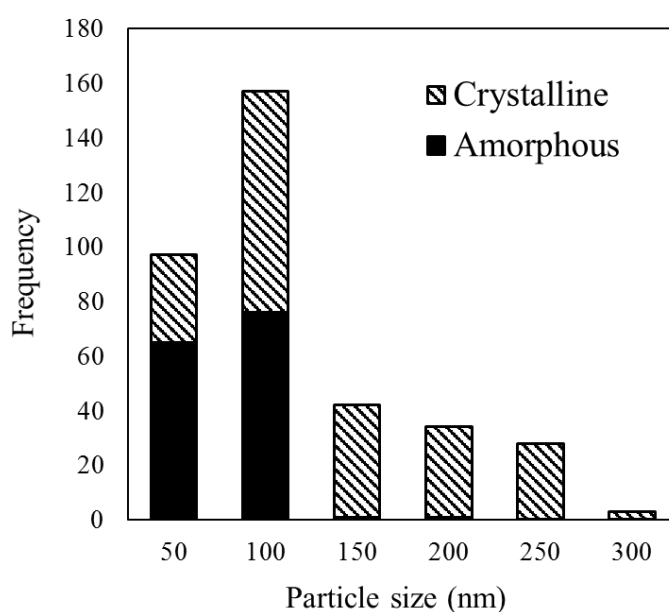


Figure 9. Size distribution of particles obtained by plasma electrolysis in 0.1 M HNO₃ at an applied voltage of 140 V. The 363 particles were analysed by TEM to distinguish the crystal structures.

4. Conclusions

The solution plasma technique was used for the synthesis of Si-NPs. The plasma discharge was generated with light emission in various electrolytes, and evaluation of the Boltzmann plot showed that the excitation temperatures ranged from 4500 to 7000 K. When the applied voltage was low, the excitation temperature and particle size were lower. The produced particle was characterized by TEM and EELS. Acidic solutions of 0.1 M HCl and HNO₃ produced Si-NPs that contained both amorphous and polycrystalline particles, among which the smaller Si-NPs tended to be amorphous. When an alkaline solution of K₂CO₃ was used, amorphous SiO₂ particles were synthesized owing to the etching of Si under the high-temperature alkaline atmosphere. Thus, the use of an acidic solution and low voltage were effective for producing smaller Si-NPs. The results will also offer insight into ways to produce Si-NPs easily and quickly. The prepared Si-NPs can be used to construct electrodes of lithium-ion batteries.

Acknowledgments

We would like to thank the "Nanotechnology Platform" Program of the Ministry of Education for allowing us to carry out transmission electron microscope observations on Si-NPs. This work was supported by a Grant-in-Aid for JSPS Fellows. The authors would like to thank Dr. Tomohiro Akiyama and Heishichiro Takahashi for many helpful discussions.

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